NSN 5961-00-442-5556

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-442-5556 **Inclosure Material:** Metal **Overall Length:** 1.402 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.557 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 700.0 forward voltage, peak **Current Rating Per Characteristic:** 22.00 amperes forward current, average absolute and 2.00 amperes zero-gate-voltage source current horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud **Specification Data:** 80131-release5169 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: